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Kind regards,

Team Nexperia

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

Rev. 8 — 28 November 2011

Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package			PNP	Package	
	NXP	JEITA	JEDEC	complement	configuration	
PDTC124EE	SOT416	SC-75	-	PDTA124EE	ultra small	
PDTC124EM	SOT883	SC-101	-	PDTA124EM	leadless ultra small	
PDTC124ET	SOT23	-	TO-236AB	PDTA124ET	small	
PDTC124EU	SOT323	SC-70	-	PDTA124EU	very small	

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified
- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
lo	output current		-	-	100	mA
R1	bias resistor 1 (input)		15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	



NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
SOT23; S	OT323; SOT416		
1	input (base)	_	
2	GND (emitter)	3	
3	output (collector)	2	1 R1 R2 sym007
SOT883			
1	input (base)		
2	GND (emitter)		
3	output (collector)	2 Transparent top view	1 R1 R2 Sym007

3. Ordering information

Type number	Package	Package					
	Name	Description	Version				
PDTC124EE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTC124EM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883				
PDTC124ET	-	plastic surface-mounted package; 3 leads	SOT23				
PDTC124EU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

4. Marking

Table 5. Marking codes	741
Type number	Marking code ^[1]
PDTC124EE	06
PDTC124EM	DX
PDTC124ET	*17
PDTC124EU	*06

[1] * = placeholder for manufacturing site code

PDTC124E_SER
Product data sheet

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

5. Limiting values

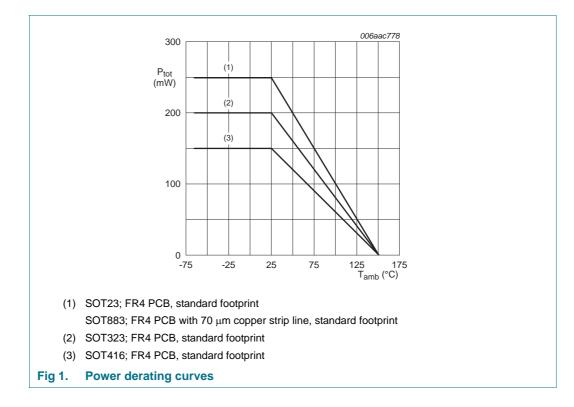
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	10	V
VI	input voltage				
	positive		-	+40	V
	negative		-	-10	V
lo	output current		-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 ms$	-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PDTC124EE (SOT416)		<u>[1][2]</u> _	150	mW
	PDTC124EM (SOT883)		[2][3]	250	mW
	PDTC124ET (SOT23)		<u>[1]</u> _	250	mW
	PDTC124EU (SOT323)		<u>[1]</u> -	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 µm copper strip line, standard footprint.

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω



6. Thermal characteristics

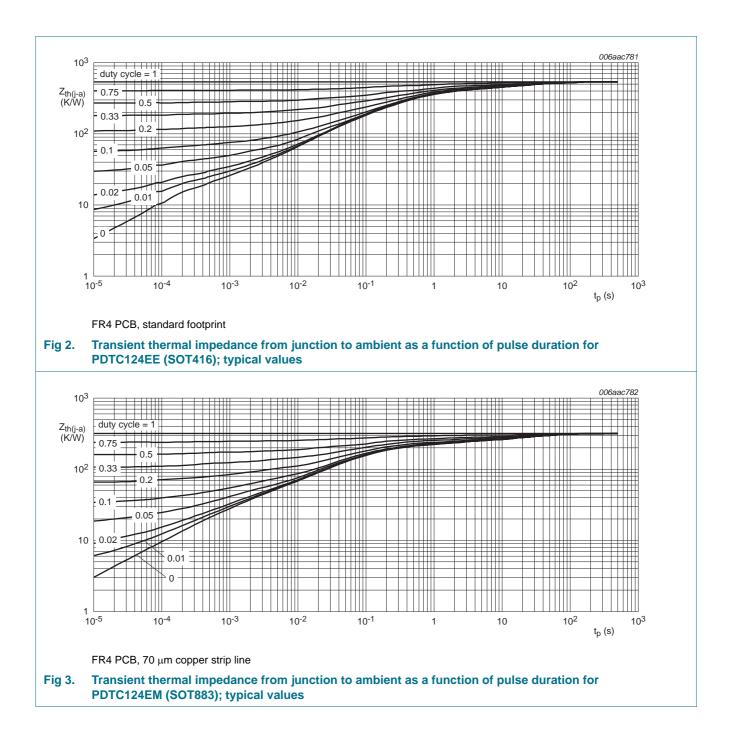
Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Mir	n Typ	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	PDTC124EE (SOT416)		[1][2]	-	830	K/W
	PDTC124EM (SOT883)		[2][3]	-	500	K/W
	PDTC124ET (SOT23)		<u>[1]</u> -	-	500	K/W
	PDTC124EU (SOT323)		<u>[1]</u> -	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

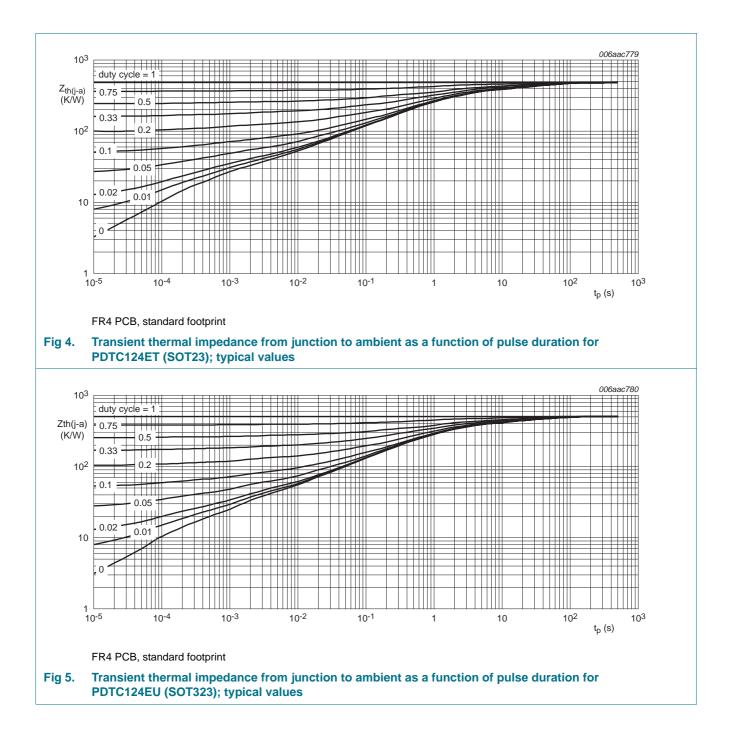
[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 μ m copper strip line, standard footprint.

PDTC124E series



PDTC124E series



NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

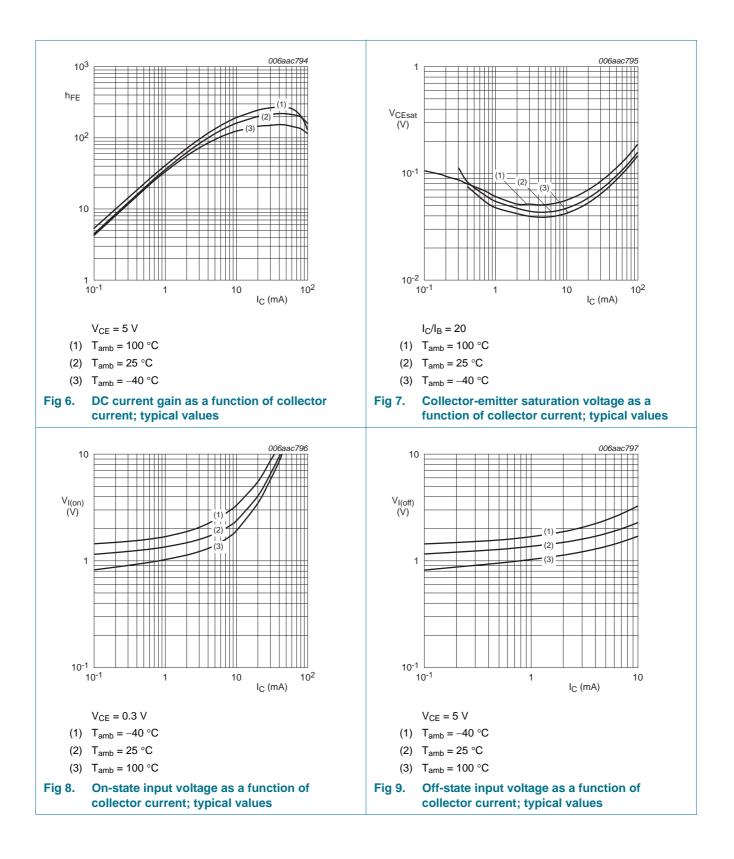
7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
I _{CEO}	collector-emitter	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}$		-	-	100	nA
	cut-off current	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C		-	-	5	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	180	μA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$		60	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = 10 mA; I_{B} = 0.5 mA		-	-	150	mV
V _{I(off)}	off-state input voltage	V_{CE} = 5 V; I_C = 100 μ A		-	1.1	0.8	V
V _{I(on)}	on-state input voltage	V_{CE} = 0.3 V; I _C = 5 mA		2.5	1.7	-	V
R1	bias resistor 1 (input)			15.4	22	28.6	kΩ
R2/R1	bias resistor ratio			0.8	1	1.2	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz		-	-	2.5	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz	<u>[1]</u>	-	230	-	MHz

[1] Characteristics of built-in transistor

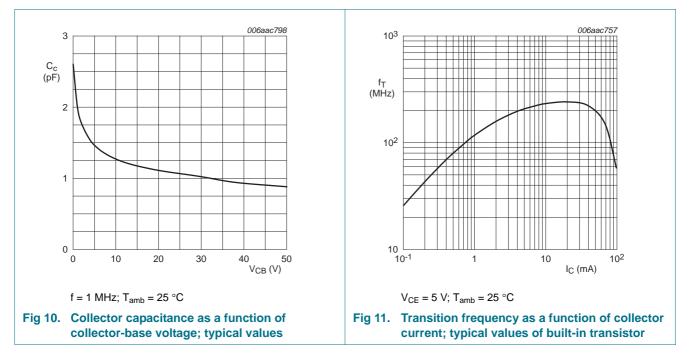
PDTC124E_SER
Product data sheet

PDTC124E series



PDTC124E series

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω



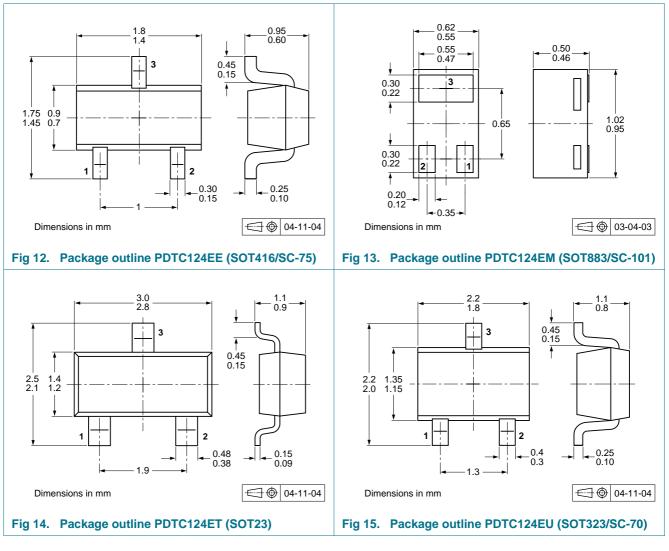
8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

9. Package outline



10. Packing information

Table 9.Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

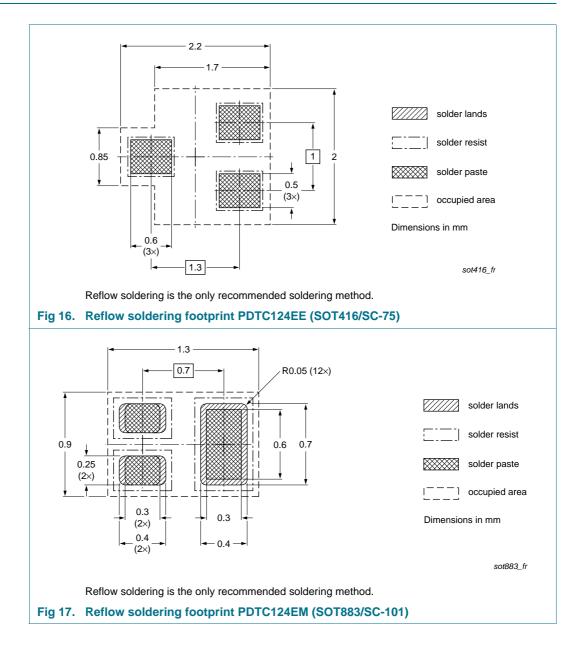
Type number	Package	Description	Packing quantity		
			3000	5000	10000
PDTC124EE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTC124EM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTC124ET	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTC124EU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

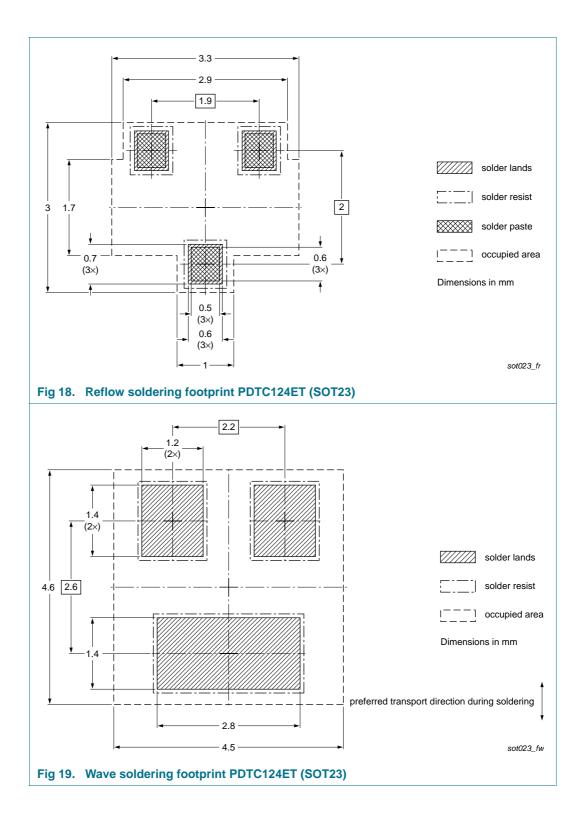
[1] For further information and the availability of packing methods, see Section 14.

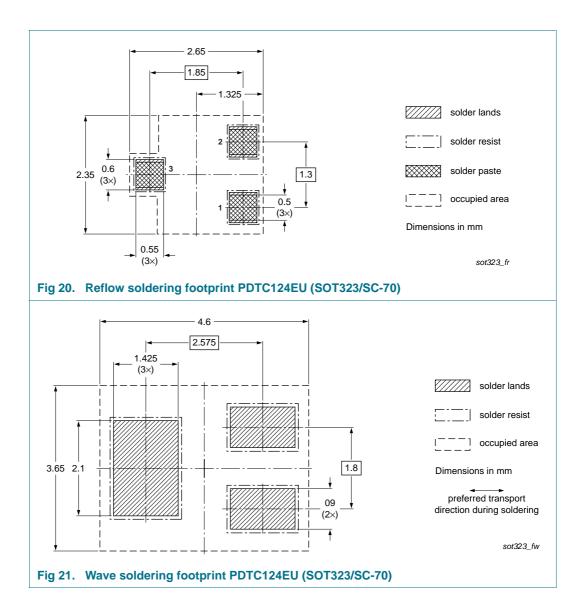
PDTC124E_SER Product data sheet

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

11. Soldering







NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PDTC124E_SER v.8	20111128	Product data sheet	-	PDTC124E_SERIES v.7			
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 						
	 Legal texts have been adapted to the new company name where appropriate. 						
	 Type numbers PDTC124EEF, PDTC124EK and PDTC124ES removed. 						
	 <u>Section 1 "Product profile"</u>: updated 						
	 <u>Section 3 "Ordering information"</u>: added 						
	• Figure 1 to 11: added						
	 <u>Table 6 "Limiting values"</u>: updated 						
	 Section 6 "Thermal characteristics": updated 						
	• <u>Table 8 "Characteristics"</u> : $V_{i(on)}$ redefined to $V_{I(on)}$ on-state input voltage, $V_{i(off)}$ redefined to $V_{I(off)}$ off-state input voltage, I_{CEO} updated, f_T added						
	Section 8 "Test information": added						
	 Section 9 "Package outline": superseded by minimized package outline drawings 						
	Section 10 "Packing information": added						
	Section 11 "	Soldering": added					
	 Section 13 " 	Legal information": update	d				
PDTC124E_SERIES v.7	20040817	Product data sheet	-	PDTC124E_SERIES v.6			
PDTC124E SERIES v.6	20030414	Product specification	-	•			

Table 10 Pevision history

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Rev. 8 — 28 November 2011

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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PDTC124E series

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

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